

SAC3125Q6

GaN Power Amplifier
0.1GHz~2GHz 39dBm

Rev1.2

Features

- Frequency: 0.1GHz~2GHz
- Gain: 15dB
- Output P_{-3dB}: 39dBm
- Supply Voltage: +28V
- Power-Added Efficiency: 45%
- Package Size: 6mm×6mm×1.1mm

Typical Applications

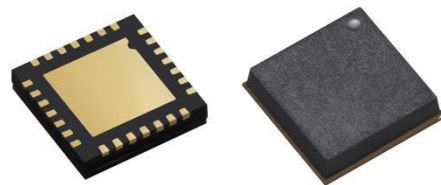
- Two-way Radio
- Satellite Communication

General Description

SAC3125Q6 is a wide band GaN power amplifier. The SAC3125Q6 provides 15 dB of gain, and 39dBm of output power for 3 dB compression and 45% PAE from a +28V supply voltage.

SAC3125Q6 is plastic SMT package that eliminates the need for wire bonding, and is compatible with high volume surface mount manufacturing techniques.

Picture



Electrical Performance

T_A=25°C, V_D=+28V, I_D=0.1A, Z₀=50Ω, CW, 50 Ohm Test Fixture

Parameter	Min.	Typ.	Max.	Units
Frequency Range	0.1~2			GHz
Small Signal Gain	13	15	—	dB
Small Signal Gain Flatness	—	±2	±2.8	dB
Reverse Isolation	—	-30	—	dB
Input Return Loss	—	-15	—	dB
Power-Added Efficiency	—	45	—	%
Output Power for 3 dB Compression (OP _{-3dB})	38	39	—	dBm
IM ₃ **	—	-23	—	dBc
Drain Voltage(V _D)	24	28	30	V
Gate Current(I _G)	—	5	8	mA
Supply Current(I _D)	—	0.45	0.65	A
Thermal Resistance*	—	12	—	°C/W

*Test condition: The device is soldered on Ro4350b t=0.168mm, with 121 filled metal vias for grounding

** Test condition: Pout / Tone = 32dBm, fc= 1GHz, Δf=4MHz

SuperApex, LLC

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Absolute Maximum Ratings

Maximum Input Power	+31dBm	Operating Temperature	-40°C~+70°C***
Channel Temperature	+215°C	Storage Temperature	-65°C~+120°C
Maximum V_D	+31V	Maximum V_G	-3.5V
Maximum Soldering Temperature	240°C 8s		

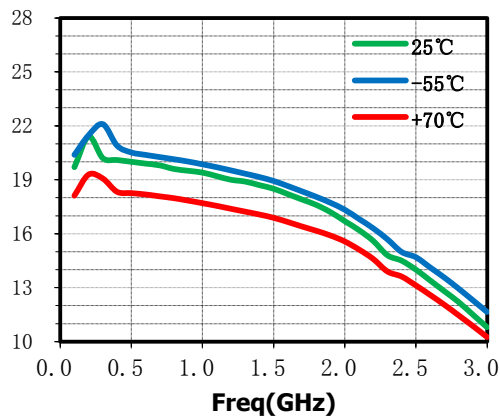
*** With sufficient heat dissipation

Typical Small Signal Performance Curve

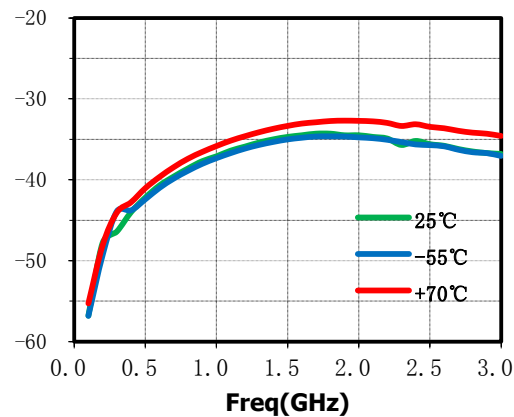
The following data are obtained using the SAC3125Q6 fixture test.

$V_D = +28V$ $I_D = 0.1A$ CW

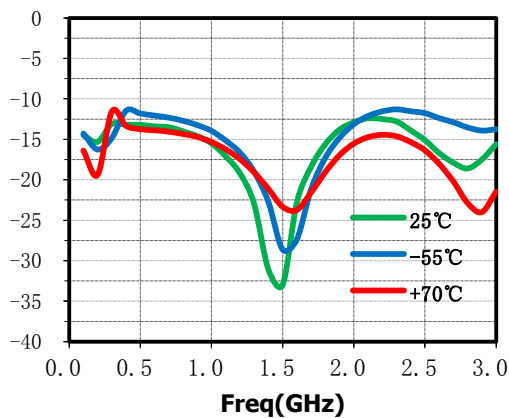
Small Signal Gain (dB) vs. Temperature



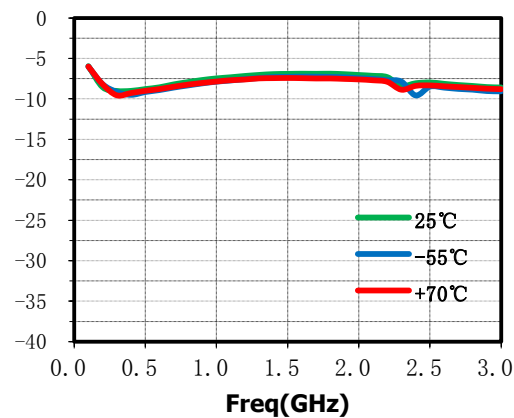
Reverse Isolation (dB) vs. Temperature



Input Return Loss (dB) vs. Temperature



Output Return Loss (dB) vs. Temperature



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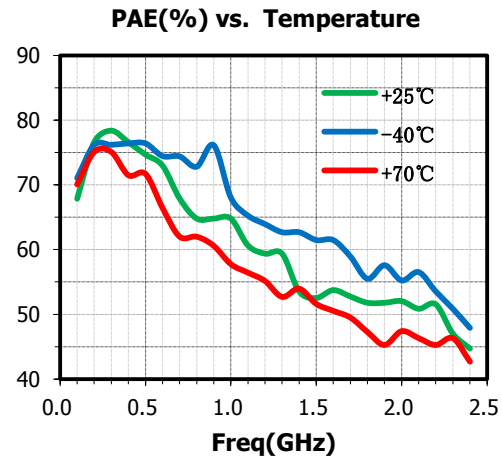
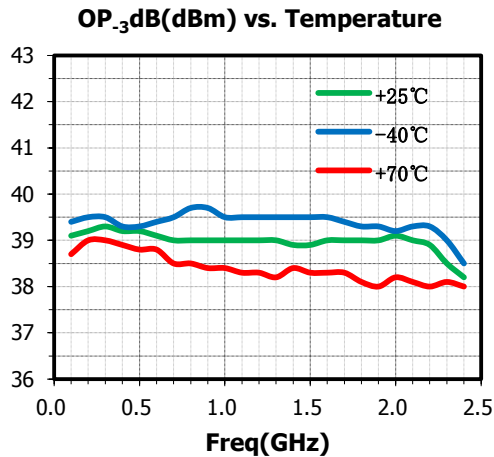
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Power and PAE Performance Curve

The results captured in the test-jig environment within connector plan, then de-embedded the housing an come back in the die plan.

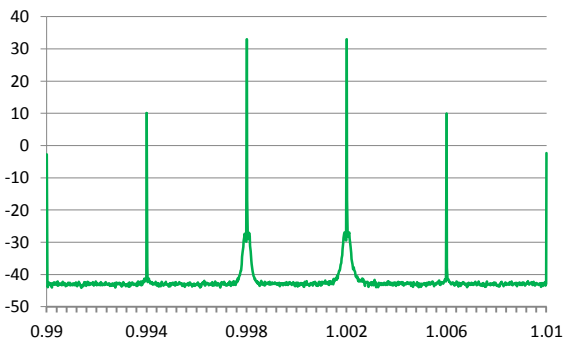
$V_D = +28V$ $I_D = 0.1A$ CW



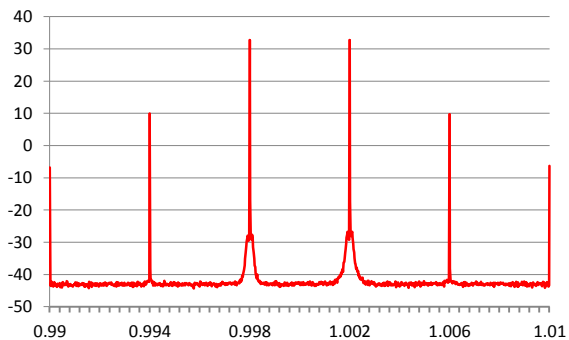
Output IM₃, Harmonic Performance Curve

The results captured in the test-jig environment within connector plan, then de-embedded the housing an come back in the die plan.

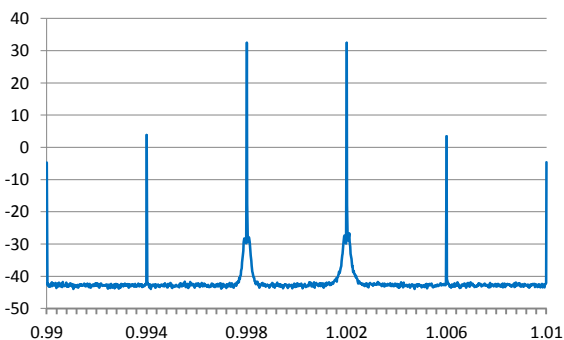
IM₃ Pout=32dBm/Tone
fc=1GHz TA=25°C



IM₃ Pout=32dBm/Tone
fc=1GHz TA=70°C



IM₃ Pout=32dBm/Tone
fc=1GHz TA=-40°C



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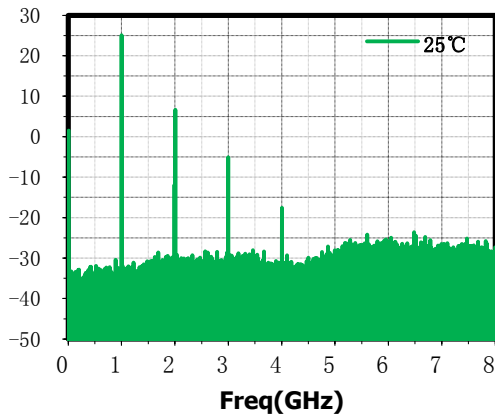
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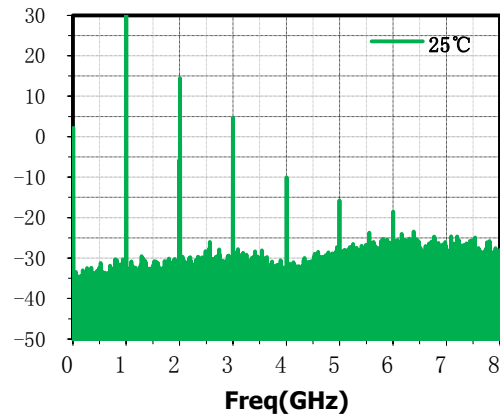
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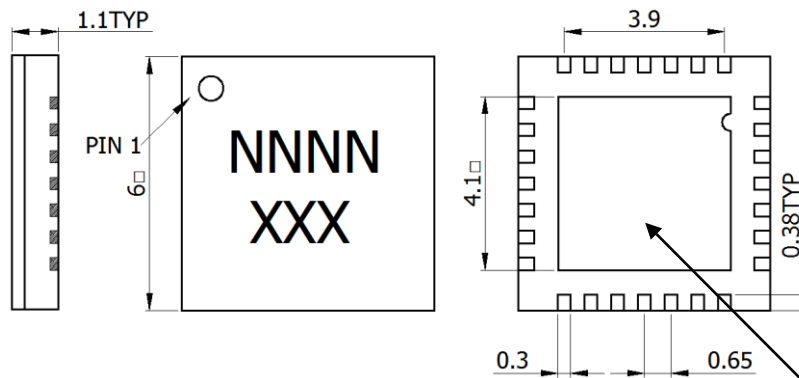
**Harmonics@
f=1GHz Pout=25dBm**



**Harmonics@
f=1GHz Pout=30dBm**



Outline Dimension (mm)



Connect to Ground

Pin Descriptions

Pin No.	function	Pin No.	function
1	Gate Supply	15	NC
2	Gate Supply	16	NC
3	NC	17	NC
4	RF Input	18	RF Output /Drain Supply
5	NC	19	NC
6	NC	20	NC
7	NC	21	NC
8	NC	22	NC
9	NC	23	NC
10	NC	24	NC
11	NC	25	NC
12	NC	26	NC
13	NC	27	NC
14	NC	28	NC

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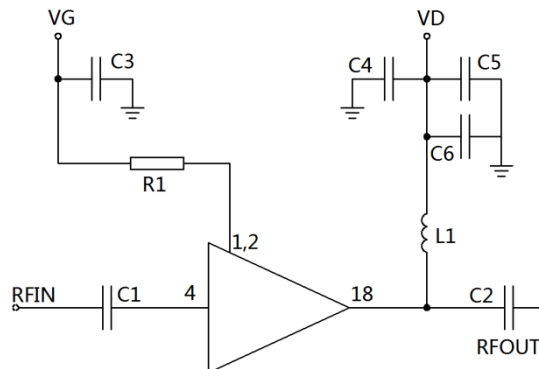
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Assembly Diagram



The other Pins keeps NC

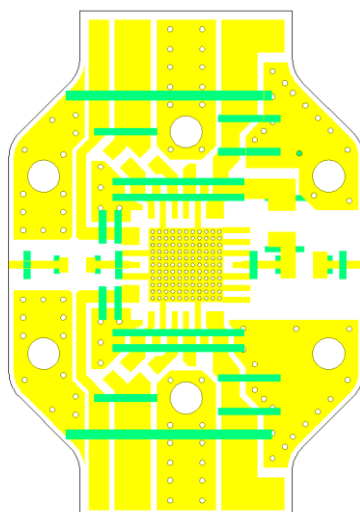
Components List

Reference Des.	Value	Part Number	Manuf.	Size
C1、C2、C6	0.01uF	GRM033R61A103KE47D	Murata	0603
C3、C4	10uF	—	—	—
C5	0.047uF	—	—	—
L1**	68nH	0805HP-82NX	Coilcraft	0805
R1*	20Ω	—	ANY	0603

*The value of R1 varies with the internal resistance of the gate bias circuit. When the internal resistance value of the gate bias circuit is less than 2Ω, R1=10 to 30 ohm is suitable.

** A larger Inductance of L1 can extend the low operation frequency to lower, Pay attention to the self-resonance of inductor.

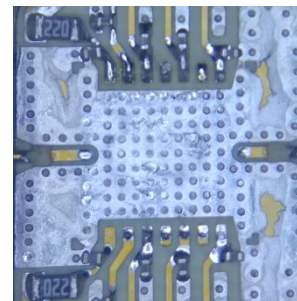
SAC3125Q6 test fixture layout



- PCB substrate: RO4350B, Thickness of substrate: 0.168mm
- Electronic copy of board design documents are available for reference.

Recommended use of this chip with special

- Put all de-coupling capacitors as closer as possible to the device.
- In order to prevent the device being destroyed by bad heat dissipation, make sure most of the ground via be filled with solder paste once device soldering work has been done.



- Use thin PCB board to short the thermal dissipation path.

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Notes

1. SAC3125Q6 is biased with a positive drain supply and negative gate supply. The recommended gate voltage is set to -2.5~-3.3V.
2. The moisture resistant grade of products is 2A, the storage environment $\leq 30^{\circ}$ C/60% RH. The surrounding workshop Life is 4 weeks.
3. After un-packing, It is necessary to bake the parts for 6 hours in 125+/-5 degree environment before welding.

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